MOTOROLA
SEMICONDUCTOR
TECHNICAL DATA

Order this data sheet by BAS116LT1/D

Advance Information

Switching Diode

This switching diode has the following features:

- Low Leakage Current Applications
- Medium Speed Switching Times
- Available in 8 mm Tape and Reel
 Use BAS116LT1 to order the 7 inch/3,000 unit reel
 Use BAS116LT3 to order the 13 inch/10,000 unit reel

BAS116LT1

Motorola Preferred Device



CASE 318-07, STYLE 8 SOT-23 (TO-236AB)



MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Continuous Reverse Voltage	V _R	75	Vdc	
Peak Forward Current	l _E	200	mAdc	
Peak Forward Surge Current	IFM(surge)	500	mA	

DEVICE MARKING

BAS116LT1 = JV

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit	
Total Device Dissipation FR-5 Board (1) TA = 25°C	PD	225	mW	
Derate above 25°C		1.8	mW/°C	
Thermal Resistance Junction to Ambient	R _{0JA}	556	°C/W	
Total Device Dissipation Alumina Substrate (2) T _A = 25°C	PD	300	mW	
Derate above 25°C		2.4	mW/°C	
Thermal Resistance Junction to Ambient	R _θ JA	417	°C/W	
Junction and Storage Temperature	TJ, T _{Stg}	-55 to +150	°C	

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	4		•	
Reverse Breakdown Voltage (I _{BR} = 100 μA)	V _(BR)	75	_	V
Reverse Voltage Leakage Current (V _R = 75 V) (V _R = 75 V, T _J = 150°C)	IR	_	5.0 80	nA
Forward Voltage (I _F = 1.0 mA) (I _F = 10 mA) (I _F = 50 mA) (I _F = 150 mA)	VF	_ _ _ _	900 1000 1100 1250	mV
Diode Capacitance (V _R = 0 V, f = 1.0 MHz)	C _D		2.0	pF
Reverse Recovery Time (I _F = I _R = 10 mA) (Figure 1)	t _{rr}	_	3.0	μs

⁽¹⁾ FR-5 = 1 0 x 0 75 x 0 062 in

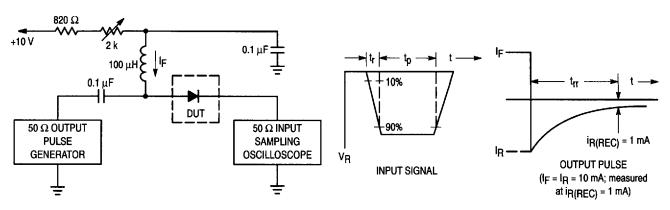
This document contains information on a new product. Specifications and information herein are subject to change without notice

Preferred devices are Motorola recommended choices for future use and best overall value.



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⁽²⁾ Alumina = 0 4 x 0 3 x 0 024 in 99 5% alumina

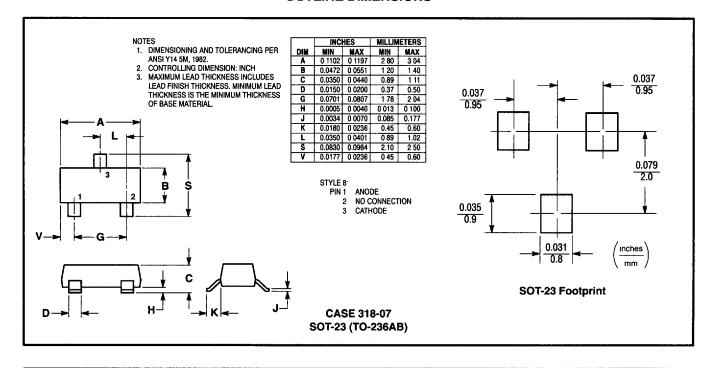


Notes: 1. A 2.0 k Ω variable resistor adjusted for a Forward Current (I_F) of 10 mA.

- 2. Input pulse is adjusted so IR(peak) is equal to 10 mA.
- 3. t_p » t_{rr}

Figure 1. Recovery Time Equivalent Test Circuit

OUTLINE DIMENSIONS



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